



PATENT  
3313-366P

IN THE U. S. PATENT AND TRADEMARK OFFICE

Applicants: Youn-Tung DAI et al. Conf: 3299  
Serial No.: 09/918,511 Art Unit: 2812  
Filed: August 1, 2001 Examiner: S. Isaac  
For: MANUFACTURING METHOD OF THIN  
FILM TRANSISTOR PANEL

AMENDMENT UNDER 37 C.F.R. §1.111

Assistant Commissioner for Patents  
Washington, DC 20231

December 2002

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DEC-6 2002  
TECHNOLOGY CENTER 2800

Sir:

In response to the Office Action mailed July 18, 2002 (Paper No. 3), the period for response being extended two months to December 18, 2002, the following amendments and remarks are respectfully submitted in connection with the above-identified application:

IN THE SPECIFICATION:

Please amend the paragraph beginning on page 3, line 19, and ending on page 4, line 2, as follows:

*Alte*  
Before bonding the transparent substrate in the invention, a black matrix can be formed on the thin film transistor structure layer. The black matrix defines the transparent range

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